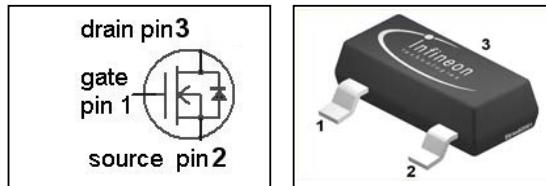


SIPMOS® Small-Signal-Transistor
Product Summary
Features

- N-channel
- Depletion mode
- dv/dt rated
- Available with $V_{GS(th)}$ indicator on reel
- Pb-free lead-plating; RoHS compliant

V_{DS}	60	V
$R_{DS(on),max}$	8	Ω
$I_{DSS,min}$	0.13	A

SOT-23



Type	Package	Pb-free	Tape and Reel Information	Marking
BSS159	PG-SOT-23	Yes	L6327: 3000 pcs/reel	SGs
BSS159	PG-SOT-23	Yes	L6906: 3000 pcs/reel sorted in $V_{GS(th)}$ bands ¹⁾	SGs

Maximum ratings, at $T_j=25$ °C, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Continuous drain current	I_D	$T_A=25$ °C	0.23	A
		$T_A=70$ °C	0.18	
Pulsed drain current	$I_{D,pulse}$	$T_A=25$ °C	0.92	
Reverse diode dv/dt	dv/dt	$I_D=0.23$ A, $V_{DS}=60$ V, $di/dt=200$ A/ μ s, $T_{j,max}=150$ °C	6	kV/ μ s
Gate source voltage	V_{GS}		± 20	V
ESD sensitivity (HBM) as per MIL-STD 883			Class 0	
Power dissipation	P_{tot}	$T_A=25$ °C	0.36	W
Operating and storage temperature	T_j, T_{stg}		-55 ... 150	°C
IEC climatic category; DIN IEC 68-1			55/150/56	

¹⁾ see table on next page and diagram 11

Parameter	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
Thermal characteristics						
Thermal characteristics	R_{thJA}	minimal footprint	-	-	350	K/W
Electrical characteristics , at $T_j=25^\circ\text{C}$, unless otherwise specified						
Static characteristics						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}}=-10\text{ V}, I_D=250\text{ }\mu\text{A}$	60	-	-	V
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=3\text{ V}, I_D=26\text{ }\mu\text{A}$	-3.5	-2.8	-2.4	
Drain-source cutoff current	$I_{\text{D}(\text{off})}$	$V_{\text{DS}}=60\text{ V},$ $V_{\text{GS}}=-10\text{ V}, T_j=25^\circ\text{C}$	-	-	0.1	μA
		$V_{\text{DS}}=60\text{ V},$ $V_{\text{GS}}=-10\text{ V}, T_j=125^\circ\text{C}$	-	-	10	
Gate-source leakage current	I_{GSS}	$V_{\text{GS}}=20\text{ V}, V_{\text{DS}}=0\text{ V}$	-	-	10	nA
On-state drain current	I_{DSS}	$V_{\text{GS}}=0\text{ V}, V_{\text{DS}}=10\text{ V}$	130	-	-	mA
Drain-source on-state resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=0\text{ V}, I_D=0.07\text{ A}$	-	3.9	8	Ω
		$V_{\text{GS}}=10\text{ V}, I_D=0.16\text{ A}$	-	1.7	3.5	
Transconductance	g_{fs}	$ V_{\text{DS}} >2 I_D R_{\text{DS}(\text{on})\text{max}},$ $I_D=0.16\text{ A}$	0.1	0.19	-	s

Threshold voltage $V_{\text{GS}(\text{th})}$ sorted in bands²⁾

J	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=3\text{ V}, I_D=26\text{ }\mu\text{A}$	-2.6	-	-2.4	V
K			-2.75	-	-2.55	
L			-2.9	-	-2.7	
M			-3.05	-	-2.85	
N			-3.2	-	-3	

²⁾ Each reel contains transistors out of one band whose identifying letter is printed on the reel label. A specific band cannot be ordered separately.

Parameter	Symbol	Conditions	Values			Unit
			min.	typ.	max.	

Dynamic characteristics

Input capacitance	C_{iss}	$V_{GS}=-10\text{ V}, V_{DS}=25\text{ V}, f=1\text{ MHz}$	-	33	44	pF
Dynamic characteristics	C_{oss}		-	8.3	11	
Reverse transfer capacitance	C_{rss}		-	3.9	5.9	
Turn-on delay time	$t_{d(on)}$		-	3.1	4.7	ns
Rise time	t_r	$V_{DD}=25\text{ V}, V_{GS}=-3\text{...}7\text{ V}, I_D=0.16\text{ A}, R_G=6\Omega$	-	2.9	4.4	
Turn-off delay time	$t_{d(off)}$		-	9	13	
Fall time	t_f		-	9	13	

Gate Charge Characteristics

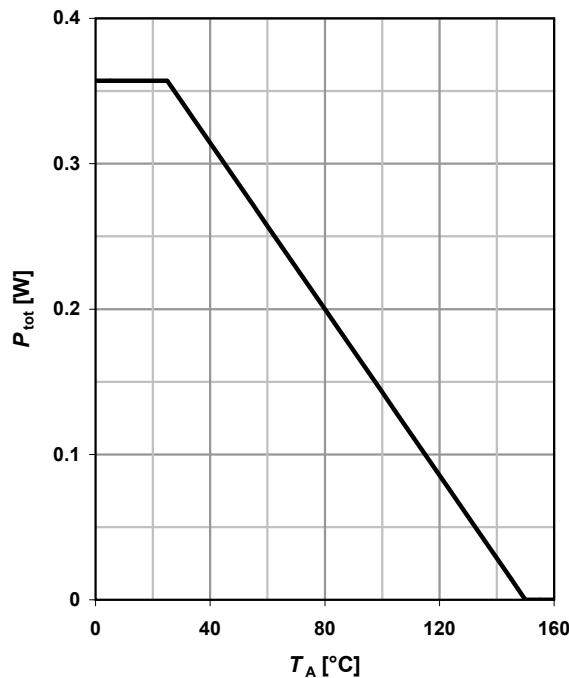
Gate to source charge	Q_{gs}	$V_{DD}=40\text{ V}, I_D=0.16\text{ A}, V_{GS}=-3\text{ to }5\text{ V}$	-	0.14	0.21	nC
Gate to drain charge	Q_{gd}		-	0.7	1.1	
Gate charge total	Q_g		-	2.2	2.9	
Gate plateau voltage	$V_{plateau}$		-	-0.14	-	

Reverse Diode

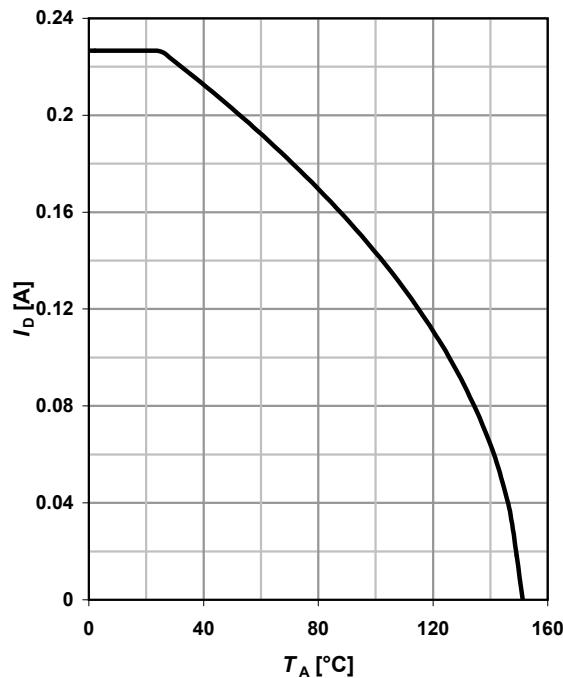
Diode continuous forward current	I_s	$T_A=25\text{ }^\circ\text{C}$	-	-	0.20	A
Diode pulse current	$I_{s,pulse}$		-	-	0.81	
Diode forward voltage	V_{SD}	$V_{GS}=-3\text{ V}, I_F=0.16\text{ A}, T_j=25\text{ }^\circ\text{C}$	-	0.79	1.2	V
Reverse recovery time	t_{rr}	$V_R=30\text{ V}, I_F=0.16\text{ A}, di_F/dt=100\text{ A}/\mu\text{s}$	-	10.4	13	ns
Reverse recovery charge	Q_{rr}		-	3.3	4.1	nC

1 Power dissipation

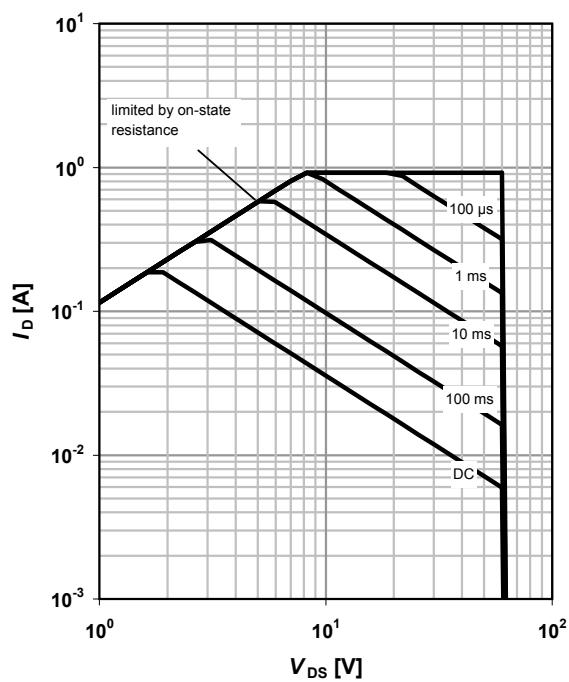
$$P_{\text{tot}} = f(T_A)$$


2 Drain current

$$I_D = f(T_A); V_{GS} \geq 10 \text{ V}$$

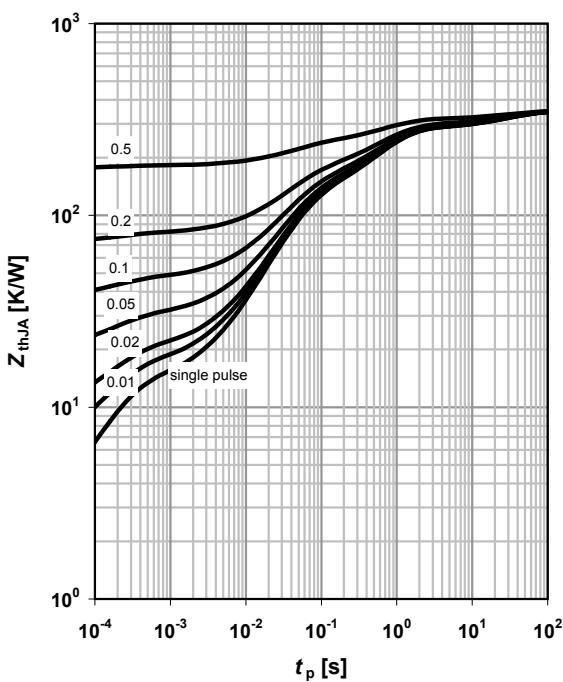

3 Safe operating area

$$I_D = f(V_{DS}); T_A = 25^\circ\text{C}; D = 0$$

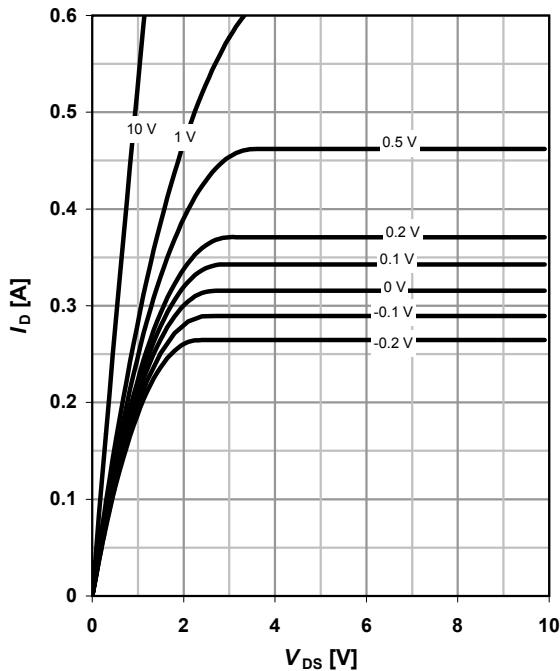

4 Max. transient thermal impedance

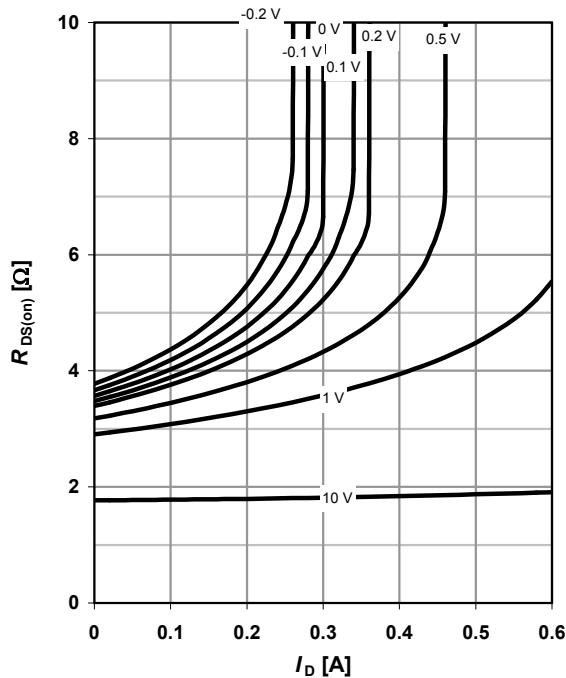
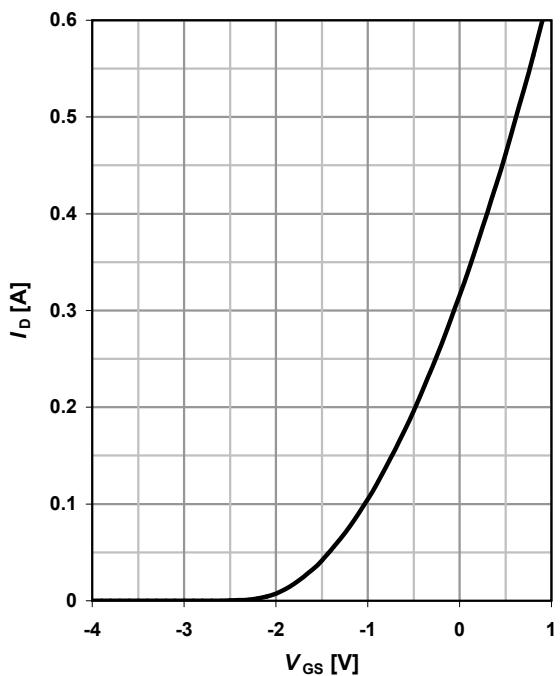
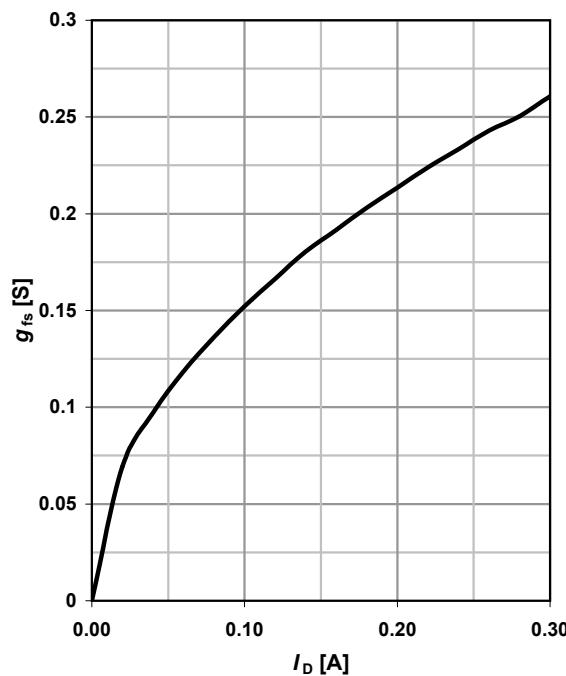
$$Z_{\text{thJA}} = f(t_p)$$

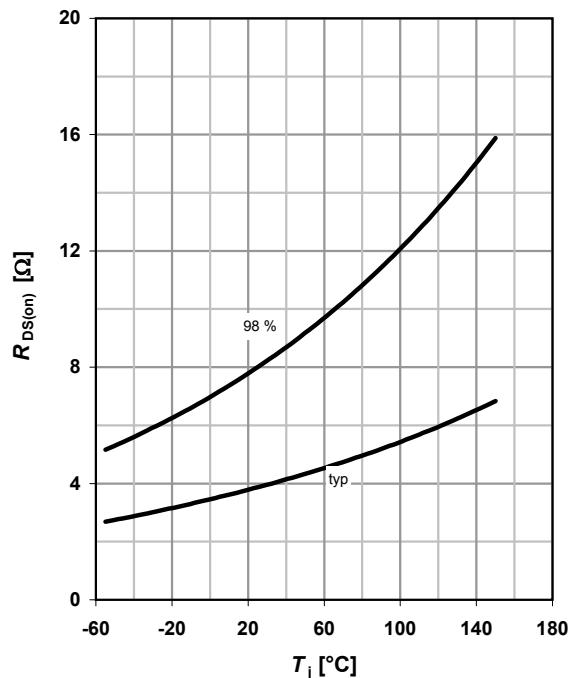
parameter: $D = t_p/T$

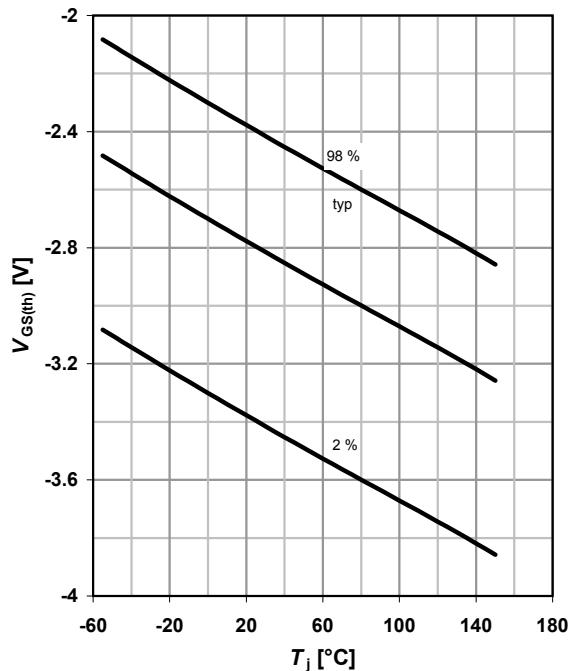
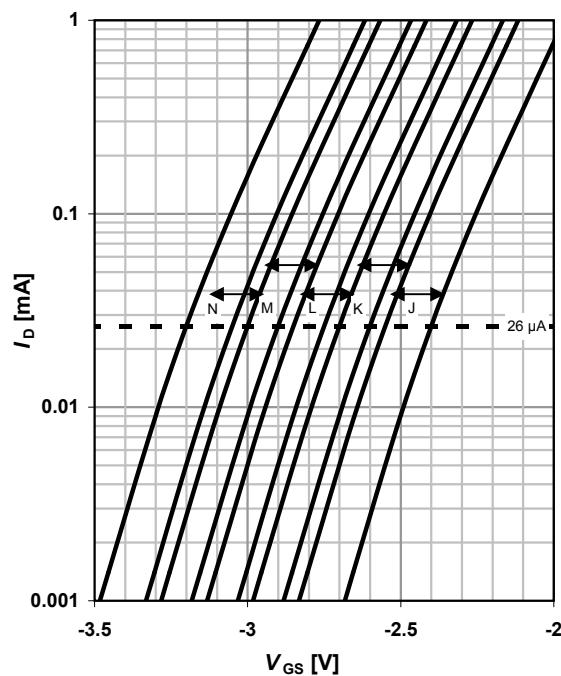
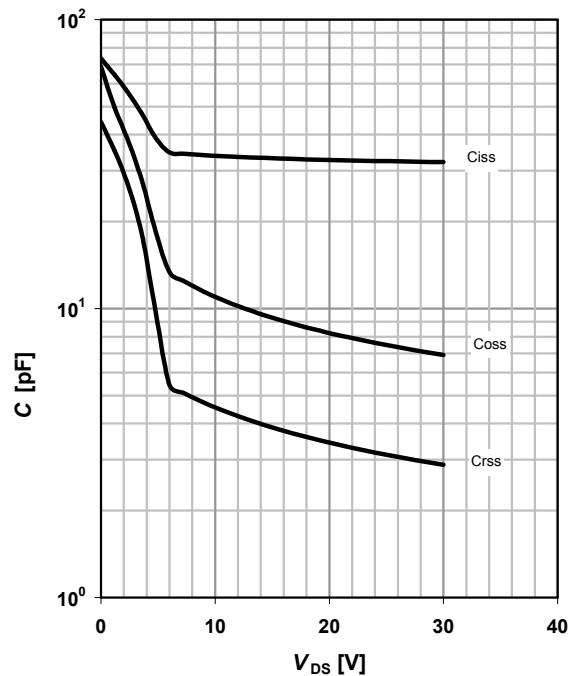


5 Typ. output characteristics
 $I_D = f(V_{DS})$; $T_j = 25^\circ\text{C}$

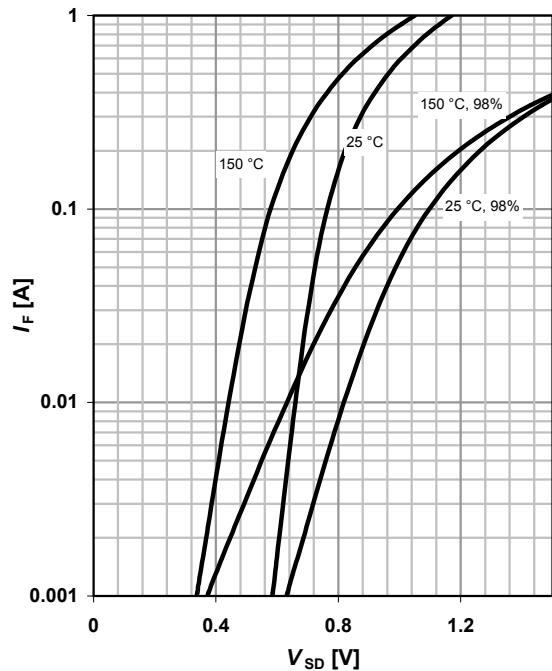
parameter: V_{GS}

6 Typ. drain-source on resistance
 $R_{DS(on)} = f(I_D)$; $T_j = 25^\circ\text{C}$

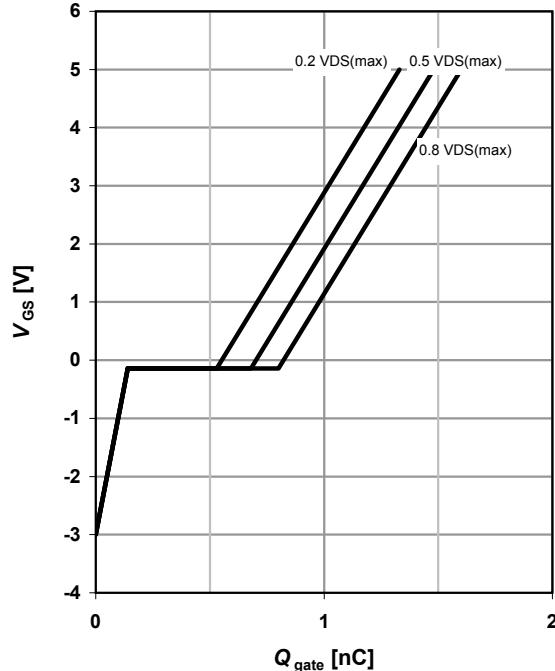
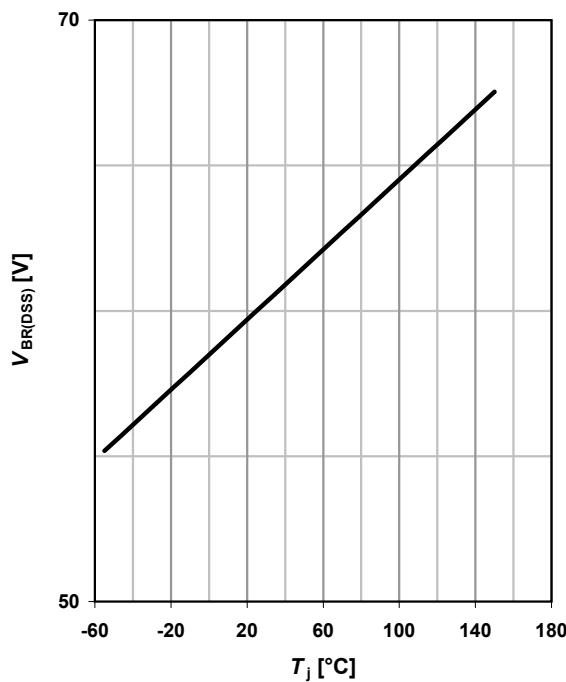
parameter: V_{GS}

7 Typ. transfer characteristics
 $I_D = f(V_{GS})$; $|V_{DS}| > 2|I_D|R_{DS(on)max}$

8 Typ. forward transconductance
 $g_{fs} = f(I_D)$; $T_j = 25^\circ\text{C}$


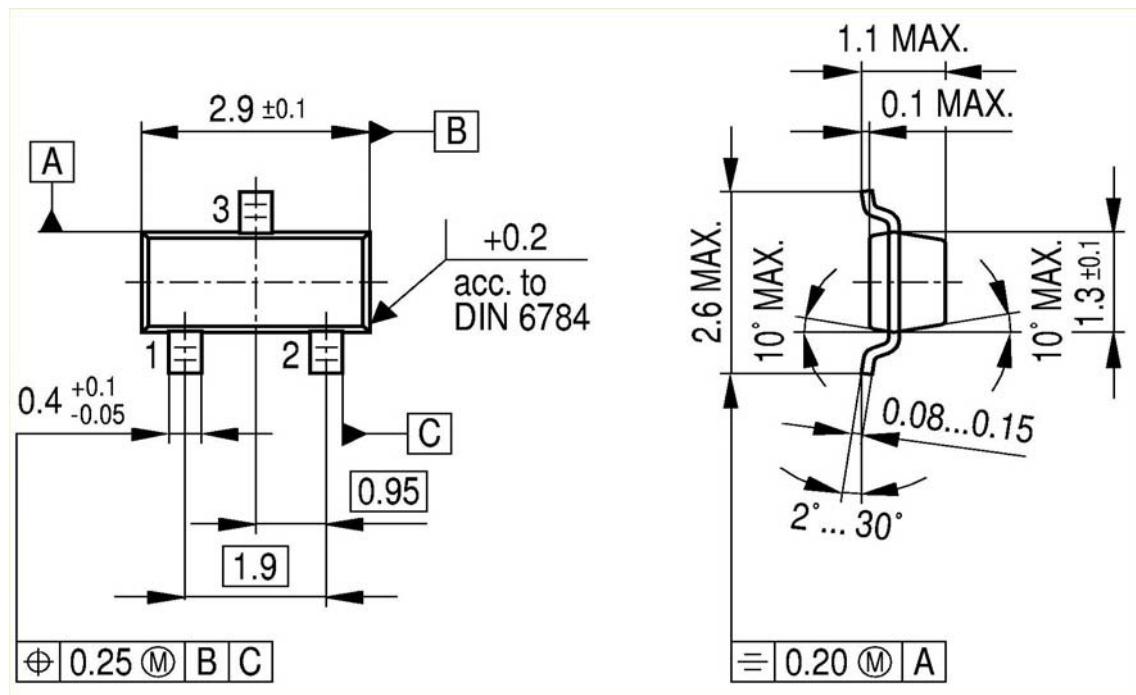
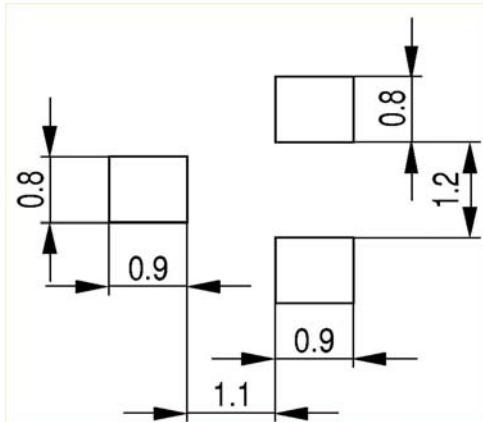
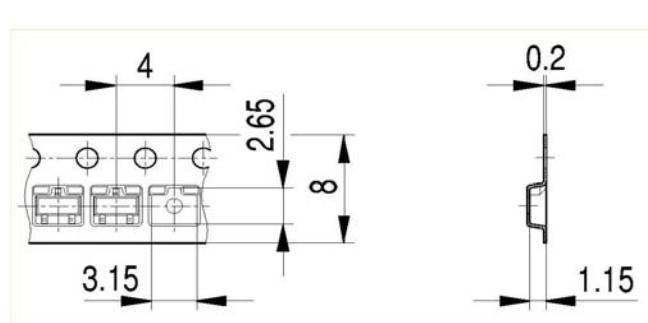
9 Drain-source on-state resistance
 $R_{DS(on)} = f(T_j); I_D = 0.07 \text{ A}; V_{GS} = 0 \text{ V}$

10 Typ. gate threshold voltage
 $V_{GS(th)} = f(T_j); V_{DS} = 3 \text{ V}; I_D = 26 \mu\text{A}$

 parameter: I_D

11 Threshold voltage bands
 $I_D = f(V_{GS}); V_{DS} = 3 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$

12 Typ. capacitances
 $C = f(V_{DS}); V_{GS} = -10 \text{ V}; f = 1 \text{ MHz}$


13 Forward characteristics of reverse diode
 $I_F = f(V_{SD})$

parameter: T_j

15 Typ. gate charge
 $V_{GS} = f(Q_{gate})$; $I_D = 0.16 \text{ A pulsed}$

parameter: V_{DD}

16 Drain-source breakdown voltage
 $V_{BR(DSS)} = f(T_j)$; $I_D = 250 \mu\text{A}$


Package Outline:

Footprint:

Packaging:


Dimensions in mm

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